

Amendments to the Specification:

On page 1 of the Specification, please amend the title as follows:

~~Low Voltage Antifuse Device and Process~~ Method of Forming an Antifuse on a Semiconductor Substrate Using Wet Oxidation of a Nitrided Substrate

On page 24 of the Specification, please amend the title as follows:

~~Low Voltage Antifuse Device and Process~~ Method of Forming an Antifuse on a Semiconductor Substrate Using Wet Oxidation of a Nitrided Substrate